RoHS

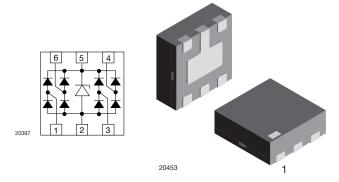
HALOGEN

FREE **GREEN**



Vishay Semiconductors

4-Line BUS-Port ESD Protection



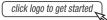
MARKING (example only)



Dot = pin 1 marking XX = date code

YY = type code (see table below)

DESIGN SUPPORT TOOLS







FEATURES

- Ultra compact LLP75-6L package
- 4-line USB ESD protection
- · Low leakage current
- Low load capacitance C_D = 1.2 pF
- ESD immunity acc. IEC 61000-4-2 ± 30 kV contact discharge ± 30 kV air discharge
- $\bullet\,$ High surge current acc. IEC 61000-4-5 $I_{pp}\,{>}\,11$ A
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu),
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

ORDERING INFORMATION							
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY				
VBUS54CV-HSF	VBUS54CV-HSF-G4-08	3000	15 000				

PACKAGE DATA								
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS		
VBUS54CV-HSF	LLP75-6L	UC	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C		

ABSOLUTE MAXIMUM RATINGS VBUS54CV-HSF						
PARAMETER	TEST CONDITIONS	SYMBOL	UNIT			
Peak pulse current	Pin 1, 3, 4 or 6 to pin 2 acc. IEC 61000-4-5, t _p = 8/20 μs/single shot	l	11	А		
	Pin 5 to pin 2 acc. IEC 61000-4-5; $t_p = 8/20 \mu s$; single shot	Іррм	13			
Peak pulse power	Pin 1, 3, 4 or 6 to pin 2 acc. IEC 61000-4-5, t _p = 8/20 μs/single shot	P _{PP}	242	W		
	Pin 5 to pin 2 acc. IEC 61000-4-5; t _p = 8/20 μs; single shot	ГРР	246			
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30			
Operating temperature	Junction temperature	T _J	-40 to +125	°C		
Storage temperature		T _{STG}	-40 to +150	°C		

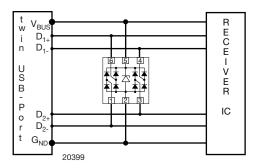
Rev. 1.3, 04-Jan-2019 Document Number: 84145

ELECTRICAL CHARACTERISTICS VBUS54CV-HSF (pin 1, 3, 4, or 6 to pin 2) (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	4	lines
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	5.5	V
Reverse voltage	at I _R = 0.1 μA	V_R	5.5	-	-	V
Reverse current	at V _{RWM} = 5.5 V	I _R	-	0.01	0.1	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	7	7.9	8.6	V
Reverse clamping voltage	at I _{PP} = 11 A	V _C	-	18	22	V
Forward clamping voltage	at I _{PP} =11 A	V _F	-	6.5	8	V
Capacitance	V_{R} (at I/O pin) = 0 V V_{R} (at pin 5) = 5 V; f = 1 MHz	C _D	-	1.2	2.5	pF
Line symmetry	Difference of the line capacitances	dC _D	-	-	0.2	pF

ELECTRICAL CHARACTERISTICS (pin 5 to pin 2) (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse stand-off voltage	Max. reverse working voltage	V_{RWM}	-	-	5.5	V
Reverse voltage	at $I_R = 0.1 \mu A$; pin 2 to pin 1	V_R	5.5	-	-	V
Reverse current	at V _{RWM} = 5.5 V	I _R	-	0.01	0.1	μΑ
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6.3	7.1	8	V
Reverse clamping voltage	at I _{PP} = 13 A	V _C	-	18	22	V
Forward clamping voltage	at I _{PP} =13 A	V _F	-	-	7	V
Capacitance	V _R (at pin 5) = 0 V; f = 1 MHz	C _D	-	190	-	pF

APPLICATION NOTE

With the VBUS54CV-HSF a double, high speed USB-port can be protected against transient voltage signals. Negative transients will be clamped close below the ground level while positive transients will be clamped close above the working range. An avalanche diode clamps the supply line (V_{BUS} at pin 5) to ground (pin 2). The high speed data lines, D_{1+} , D_{2+} , D_{1-} and D_{2-} , are connected to pin 1, 3, 4 and 6. As long as the signal voltage on the data lines is between the ground- and the V_{BUS} -level, the low capacitance PN-diodes offer a very high isolation to V_{BUS} , ground and to the other data lines. But as soon as any transient signal exceeds this working range, one of the PN-diodes gets in the forward mode and clamps the transient to ground or the avalanche break through voltage level.



TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

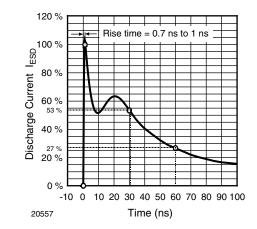


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω /150 pF)

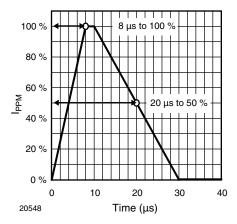


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

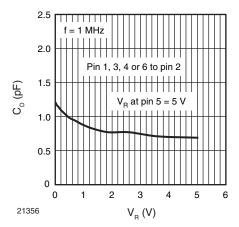


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

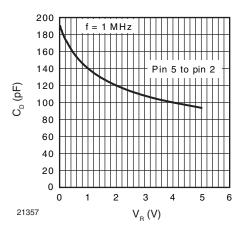


Fig. 4 - Typical Capacitance C_{D} vs. Reverse Voltage V_{R}

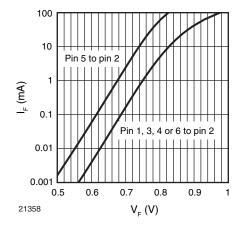


Fig. 5 - Typical Forward Current I_F vs. Forward current I_R

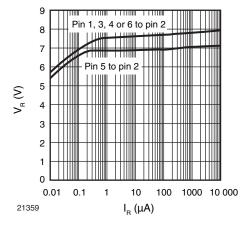


Fig. 6 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

www.vishay.com Vishay Semiconductors

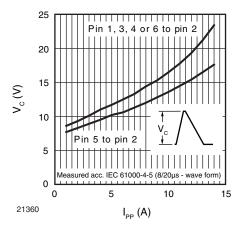


Fig. 7 - Typical Peak Clamping Voltage vs. Peak Pulse Current I_{PP}

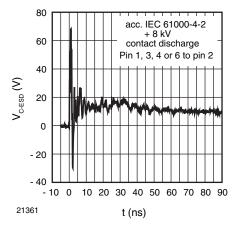


Fig. 8 - Typical Clamping Performance at 8 kV Contact Discharge (acc. IEC 61000-4-2)

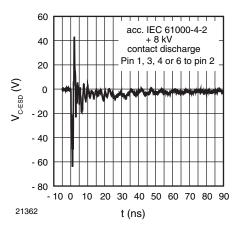


Fig. 9 - Typical Clamping Performance at 8 kV Contact Discharge (acc. IEC 61000-4-2)

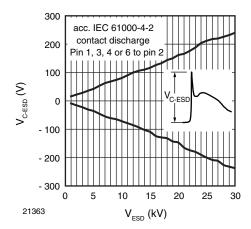
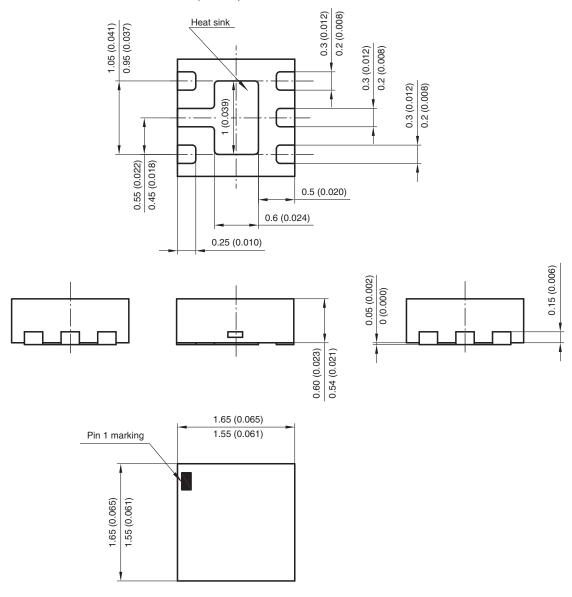
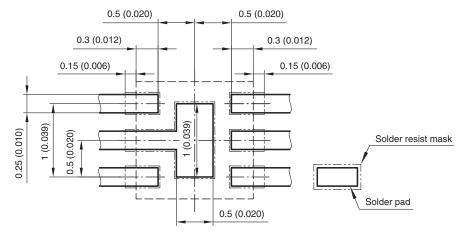


Fig. 10 - Typical Peak Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)

PACKAGE DIMENSIONS in millimeters (inches): LLP75-6L



Foot print recommendation:



Document no.:S8-V-3906.02-010 (4) Created - Date: 04. MAY 2005

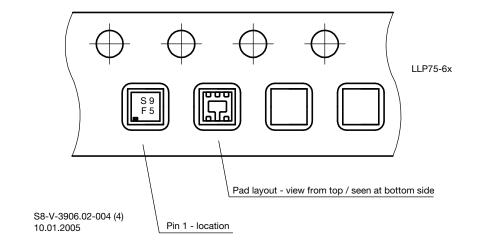
Rev. 4 - Date: 21. March 2006

20454

Rev. 1.3, 04-Jan-2019

5 Document Number: 84145







Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)